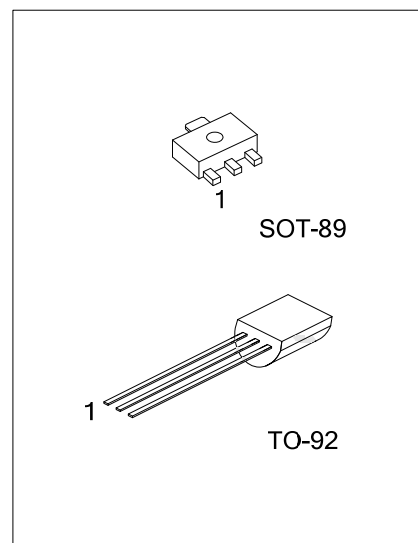


**MPSA44/45****NPN SILICON TRANSISTOR****HIGH VOLTAGE TRANSISTOR**■ **FEATURES**

* Collector-Emitter Voltage:

 $V_{CE0}=400V$ (UTC **MPSA44**) $V_{CE0}=350V$ (UTC **MPSA45**)

* Collector Current up to 300mA

■ **ORDERING INFORMATION**

Ordering Number		Package	Pin Assignment			Packing
Lead Free	Halogen Free		1	2	3	
MPSA44L-AB3-R	MPSA44G-AB3-R	SOT-89	B	C	E	Tape Reel
MPSA45L-AB3-R	MPSA45G-AB3-R	SOT-89	B	C	E	Tape Reel
MPSA44L-T92-B	MPSA44G-T92-B	TO-92	E	B	C	Tape Box
MPSA44L-T92-K	MPSA44G-T92-K	TO-92	E	B	C	Bulk
MPSA44L-T92-R	MPSA44G-T92-R	TO-92	E	B	C	Tape Reel
MPSA45L-T92-B	MPSA45G-T92-B	TO-92	E	B	C	Tape Box
MPSA45L-T92-K	MPSA45G-T92-K	TO-92	E	B	C	Bulk
MPSA45L-T92-R	MPSA45G-T92-R	TO-92	E	B	C	Tape Reel

MPSA44L-AB3-R (1)Packing Type (2)Package Type (3)Lead Free	(1) B: Tape Box, K: Bulk, R: Tape Reel (2) AB3: SOT-89, T92: TO-92 (3) G: Halogen Free, L: Lead Free
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■ ABSOLUTE MAXIMUM RATING

PARAMETER	SYMBOL	RATINGS	UNIT
Collector-Base Voltage	V_{CBO}	500	V
		400	
Collector-Emitter Voltage	V_{CEO}	400	V
		350	
Emitter-Base Voltage	V_{EBO}	6	V
Collector Current	I_C	300	mA
Collector Dissipation	P_C	500	mW
		625	
Junction Temperature	T_J	125	°C
Operating Temperature	T_{OPR}	-20 ~ +85	°C
Storage Temperature	T_{STG}	-40 ~ +150	°C

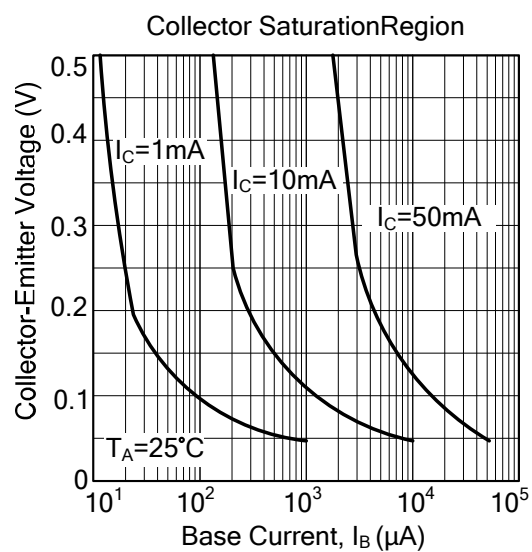
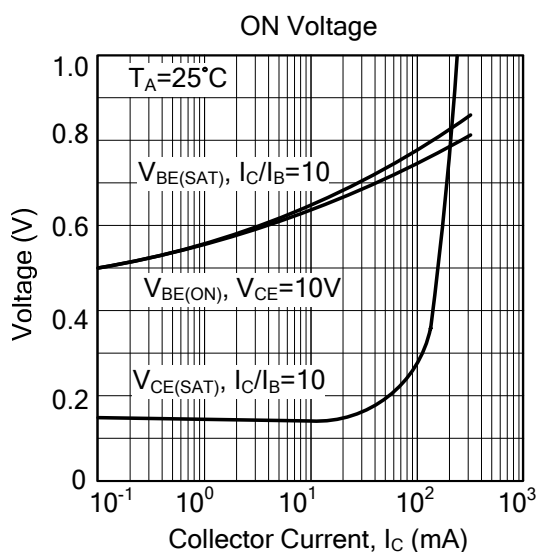
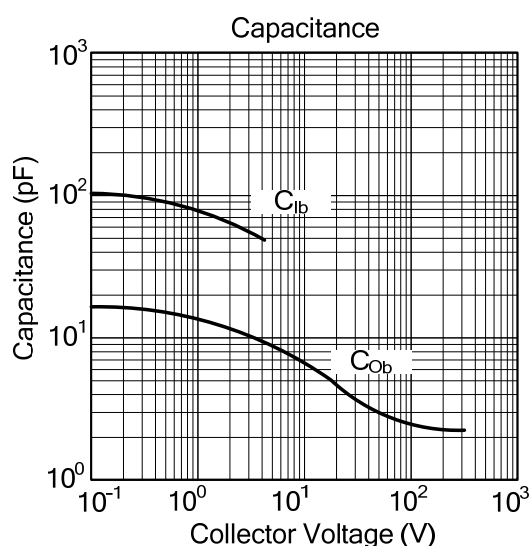
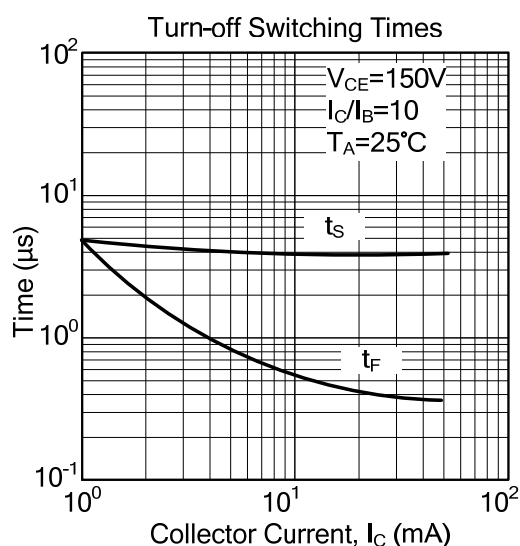
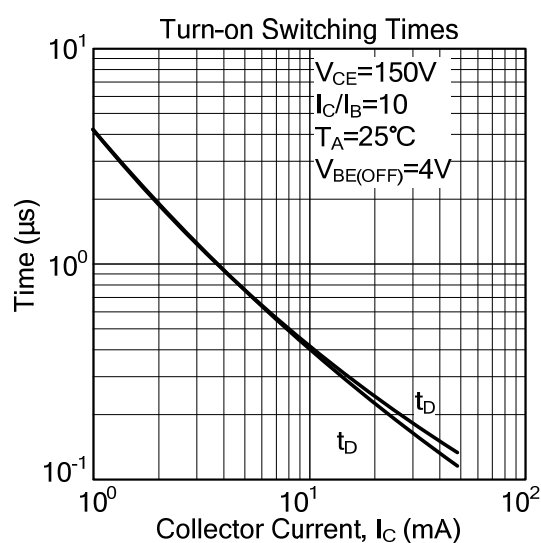
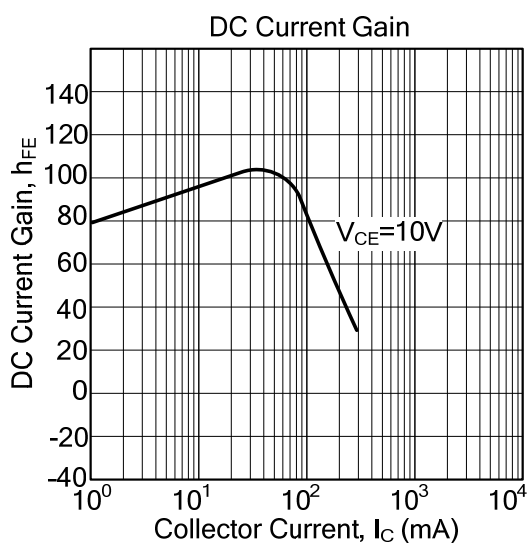
Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ ELECTRICAL CHARACTERISTICS ($T_J=25^{\circ}\text{C}$, unless otherwise specified)

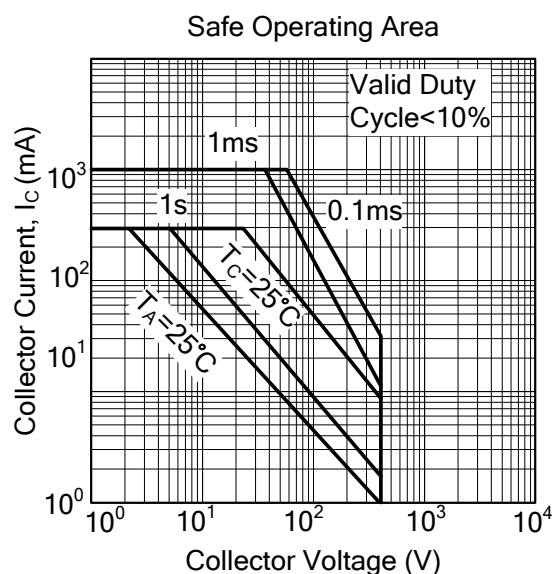
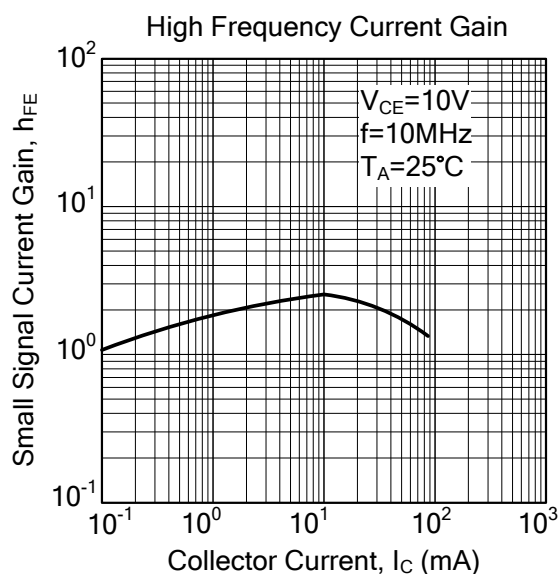
PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Collector-Base Breakdown Voltage	BV_{CBO}	$I_C=100\mu\text{A}, I_E=0$	500			V
			400			
Collector-Emitter Breakdown Voltage	BV_{CEO}	$I_C=1\text{mA}, I_B=0$	400			V
			350			
Emitter-Base Breakdown Voltage	BV_{EBO}	$I_E=100\mu\text{A}, I_C=0$	6			V
Collector Cutoff Current	I_{CBO}	$V_{CB}=400\text{V}, I_E=0$			0.1	μA
		$V_{CB}=320\text{V}, I_E=0$			0.1	
Collector Cutoff Current	I_{CEO}	$V_{CE}=400\text{V}, I_B=0$			0.5	μA
		$V_{CE}=320\text{V}, I_B=0$			0.5	
Emitter Cutoff Current	I_{EBO}	$V_{EB}=4\text{V}, I_C=0$			0.1	μA
ON CHARACTERISTICS						
DC Current Gain (Note)	h_{FE}	$V_{CE}=10\text{V}, I_C=1\text{mA}$	40		240	
		$V_{CE}=10\text{V}, I_C=10\text{mA}$	82		240	
		$V_{CE}=10\text{V}, I_C=50\text{mA}$	45		240	
		$V_{CE}=10\text{V}, I_C=100\text{mA}$	40		240	
Collector-Emitter Saturation Voltage	$V_{CE(SAT)}$	$I_C=1\text{mA}, I_B=0.1\text{mA}$			0.4	V
		$I_C=10\text{mA}, I_B=1\text{mA}$			0.5	
		$I_C=50\text{mA}, I_B=5\text{mA}$			0.75	
Base-Emitter Saturation Voltage	$V_{BE(SAT)}$	$I_C=10\text{mA}, I_B=1\text{mA}$			0.75	V
SMALL-SIGNAL CHARACTERISTICS						
Current Gain Bandwidth Product	f_T	$V_{CE}=20\text{V}, I_C=10\text{mA}, f=100\text{MHz}$	50			MHz
Output Capacitance	C_{OB}	$V_{CB}=20\text{V}, I_E=0, f=1\text{MHz}$			7	pF

Note: Pulse test: $PW < 300\mu\text{s}$, Duty Cycle $< 2\%$

TYPICAL CHARACTERISTICS



■ TYPICAL CHARACTERISTICS(Cont.)



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